



Tfw

Docket No.: 8734.225.00  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of:  
Seok-Woo LEE

Customer No.: 30827

Application No.: 10/648,401

Confirmation No. 5327

Filed: August 27, 2003

Art Unit: 2812

For: METHOD OF FABRICATING TOP GATE  
TYPE THIN FILM TRANSISTOR HAVING  
LOW TEMPERATURE POLYSILICON

Examiner: Stanetta D. Isaac

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT**

Sir:

In response to the Non-Final Office Action dated June 20, 2005 Applicant hereby requests entry of the following amendments.

**INTRODUCTORY COMMENTS**

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks** begin on page 9 of this paper.